

LM48860 Boomer® Audio Power Amplifier Series

Ground-Referenced, Ultra Low Noise, Fixed Gain Stereo Headphone Amplifier

General Description

The LM48860 is a ground referenced, fixed-gain audio power amplifier capable of delivering 40mW per channel of continuous average power into a 16Ω single-ended load with less than 1% THD+N from a 3V power supply.

The LM48860 features a new circuit technology that utilizes a charge pump to generate a negative reference voltage. This allows the outputs to be biased about ground, thereby eliminating output-coupling capacitors typically used with normal single-ended loads.

Boomer audio power amplifiers were designed specifically to provide high quality output power with a minimal amount of external components. The LM48860 does not require output coupling capacitors or bootstrap capacitors, and therefore is ideally suited for mobile phone and other low voltage applications where minimal power consumption is a primary requirement.

The LM48860 features a low-power consumption shutdown mode selectable for either channel separately. This is accomplished by driving either the $\overline{SD_RC}$ (Shutdown Right Channel) or $\overline{SD_LC}$ (Shutdown Left Channel) (or both) pins with logic low, depending on which channel is desired shutdown. Additionally, the LM48860 features an internal thermal shutdown protection mechanism.

The LM48860 contains advanced pop & click circuitry that eliminates noises which would otherwise occur during turn-on and turn-off transitions.

The LM48860 has an internal fixed gain of 1.5V/V.

Key Specifications

	PSRR at 217Hz ($V_{DD} = 3.0V$)	80dB (typ)
--	-----------------------------------	------------

Stereo Power Output at V_{DD} = 3V R_I = 16Ω, THD+N = 1%

 R_L = 16Ω, THD+N = 1% 40mW (typ) Shutdown Current 0.1μA (typ)

■ Internal Fixed Gain 1.5V/V (typ)

Operating Voltage 2.0V to 5.5V

Features

- Fixed logic levels with supply voltage
- Ground referenced outputs
- High PSRR
- Available in space-saving micro SMD package
- Ultra low current shutdown mode
- Improved pop & click circuitry eliminates noises during turn-on and turn-off transitions
- No output coupling capacitors, snubber networks, bootstrap capacitors, or gain-setting resistors required
- Shutdown either channel independently

Applications

- Mobile Phones
- MP3 Players
- PDAs
- Portable electronic devices
- Notebook PCs

Typical Application

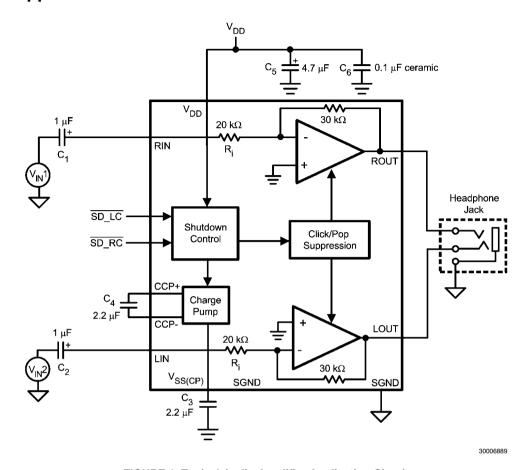
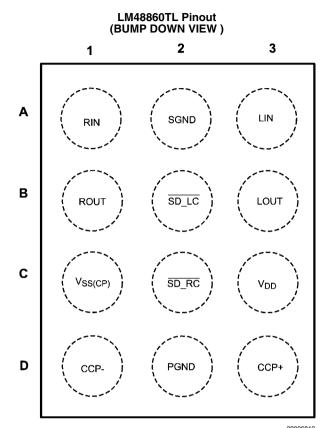


FIGURE 1. Typical Audio Amplifier Application Circuit

Connection Diagram



Top View Order Number LM48860TL See NS Package Number TLA12XXX

Pin Descriptions

Pin	Name	Function	
A1	RIN	ight Channel Input	
A2	SGND	Signal Ground	
A3	LIN	Left Channel Input	
B1	ROUT	Right Channel Output	
B2	SD_LC	Active Low Shutdown, Left Channel	
В3	LOUT	Left Channel Output	
C1	V _{SS(CP)}	Charge Pump Voltage Output	
C2	SD_RC Active-Low Shutdown, Right Channel		
C3	C3 V _{DD} Supply Voltage		
D1	CCP-	Negative Terminal - Charge Pump Flying Capacitor	
D2	PGND	Power Ground	
D3	CCP+	Positive Terminal - Charge Pump Flying Capacitor	

3

Absolute Maximum Ratings (Notes 2, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage 6.0V Storage Temperature -65°C to +150°C

Input Voltage -0.3V to V_{DD}
Power Dissipation (Note 3) Internally Limited

ESD Rating(Note 4) 2000V ESD Rating (Note 5) 200V Junction Temperature 150°C Thermal Resistance

 θ_{JA} (typ) TLA12XXX 59.3°C/W

Operating Ratings

Temperature Range

 $T_{MIN} \le T_A \le T_{MAX}$ $-40^{\circ}C \le T_A \le 85^{\circ}C$ Supply Voltage (V_{DD}) $2.0V \le V_{DD} \le 5.5V$

Electrical Characteristics $V_{DD} = 3V$ (Notes 1, 2)

The following specifications apply for V_{DD} = 3V and 16 Ω load unless otherwise specified. Limits apply to T_A = 25°C.

			LM48860		11-44-	
Symbol	Parameter	Conditions	Typical (Note 6)	Limit (Note 7)	Units (Limits)	
1	Quiescent Power Supply Current	$V_{DD} = 3.0V,$ $V_{IN} = 0V,$ inputs terminated both channels enabled	4	5.5	mA (max)	
I _{DD}	Full Power Mode	$V_{DD} = 5.0V,$ $V_{IN} = 0V,$ inputs terminated both channels enabled	4.2		mA	
		SD_LC = SD_RC= GND	0.1	1	μA (max)	
I _{SD}	Shutdown Current	$SD_LC = SD_RC = GND,$ $V_{DD} = 5.0V$	0.1	1	μA (max)	
V _{os}	Output Offset Voltage	$R_L = 32\Omega$, $V_{IN} = 0V$	0.7	5.5	mV (max)	
A _V	Voltage Gain		-1.5		V/V	
ΔA_V	Channel-to-channel Gain Matching		1		%	
R _{IN}	Input Resistance		20	15 25	kΩ (min) kΩ (max)	
	Output Power	THD+N = 1% (max); f = 1kHz, R_L = 16 Ω , (two channels in phase)	40	35	mW (min)	
P _O		THD+N = 1% (max); f = 1kHz, R_L = 32 Ω , (two channels in phase)	50	40	mW (min)	
TUD N	Total Harmonic Distortion +	$P_O = 20$ mW, $f = 1$ kHz, $R_L = 16\Omega$ (two channels in phase)	0.025		%	
THD+N	Noise	P_O = 25mW, f = 1kHz, R_L = 32 Ω (two channels in phase)	0.014		%	
		V _{RIPPLE} = 200mV _{PP} , Input Referred			•	
PSRR	Power Supply Rejection Ratio	f = 217Hz	80	73	dB (min)	
ronn	Full Power Mode	f = 1kHz	75		dB	
		f = 20kHz	60		dB	
SNR	$ \begin{array}{ll} & & R_L = 32\Omega, P_{OUT} = 50 \text{mW}, \\ \text{Signal-to-Noise Ratio} & & \text{f} = 1 \text{kHz}, \text{BW} = 20 \text{Hz to } 22 \text{kHz}, \\ & \text{A-weighted} \end{array} $		105		dB	
V _{IH}	Shutdown Input Voltage High	V _{DD} = 2.0V to 5.5V		1.2	V (min)	
V _{IL}	Shutdown Input Voltage Low	V _{DD} = 2.0V to 5.5V		0.45	V (max)	
X _{TALK}	Crosstalk $\begin{aligned} R_L &= 16\Omega, P_O = 1.6 \text{mW}, \\ f &= 1 \text{kHz} \end{aligned}$		75		dB	
€os	Output Noise	A-weighted filter, V _{IN} = 0V	8		μV	

	Parameter	Conditions	LM48860		Unite
Symbol			Typical (Note 6)	Limit (Note 7)	Units (Limits)
Z _{OUT}	Output Impedance	V _{SD} = GND Input Terminated Input not terminated SD_LC = SD_RC = GND	30 30	20	kΩ (min) kΩ
IL	Input Leakage		±0.1		nA

Note 1: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.

Note 2: The Electrical Characteristics tables list guaranteed specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not guaranteed.

Note 3: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX} , θ_{JA} , and the ambient temperature, T_A . The maximum allowable power dissipation is $P_{DMAX} = (T_{JMAX} - T_A) / \theta_{JA}$ or the number given in *Absolute Maximum Ratings*, whichever is lower. For the LM48860, see power derating curves for additional information.

Note 4: Human body model, applicable std. JESD22-A114C.

Note 5: Machine model, applicable std. JESD22-A115-A.

Note 6: Typical values represent most likely parametric norms at $T_A = +25$ °C, and at the Recommended Operation Conditions at the time of product characterization and are not guaranteed.

Note 7: Datasheet min/max specification limits are guaranteed by test or statistical analysis.

Note 8: θ_{IA} value is measured with the device mounted on a PCB with a 1.5" x 1.375", 1oz copper heatsink.

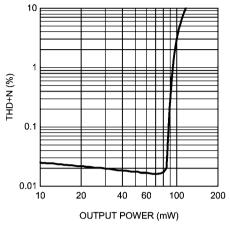
External Components Description

(Figure 1)

Components		Functional Description			
1.	C ₁	Input coupling capacitor which blocks the DC voltage at the amplifier's input terminals. Also creates a high pass-pass filter with R_i at $f_C = 1/(2R_iC_1)$. Refer to the section Proper Selection of External Components , for an explanation of how to determine the value of C_1 .			
2.	C ₂	Input coupling capacitor which blocks the DC voltage at the amplifier's input terminals. Also creates a high passpass filter with R_i at $f_C = 1/(2R_iC_2)$. Refer to the Power Supply Bypassing section for an explanation of how to determine the value of C_2 .			
3.	C ₃	Output capacitor. Low ESR ceramic capacitor (≤100mΩ)			
4.	C ₄	Flying capacitor. Low ESR ceramic capacitor (≤100mΩ)			
5.	C ₅	Tantalum capacitor. Supply bypass capacitor which provides power supply filtering. Refer to the Power Supply Bypassing section for information concerning proper placement and selection of the supply bypass capacitor.			
6.	C ₆	Ceramic capacitor. Supply bypass capacitor which provides power supply filtering. Refer to the Power Supply Bypassing section for information concerning proper placement and selection of the supply bypass capacitor.			

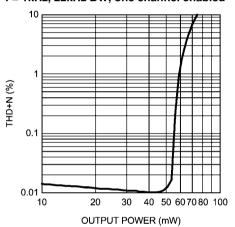
Typical Performance Characteristics

THD+N vs Output Power $V_{DD}=3V,\,R_L=16\Omega$ f = 1kHz, 22kHz BW, one channel enabled



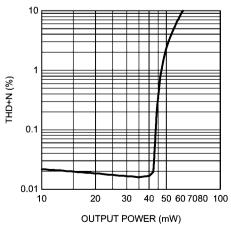
300068d2

THD+N vs Output Power $V_{DD}=3V,\,R_{L}=32\Omega$ f = 1kHz, 22kHz BW, one channel enabled



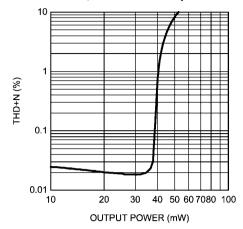
300068d3

THD+N vs Output Power $V_{DD}=3.6V,\,R_L=16\Omega$ f = 1kHz, 22kHz BW, one channel enabled



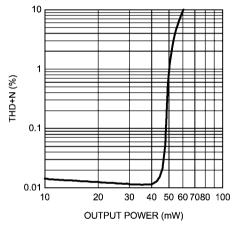
300068c8

THD+N vs Output Power V_{DD} = 3V, R_L = 16 Ω , f = 1kHz 22kHz BW, two channels in phase



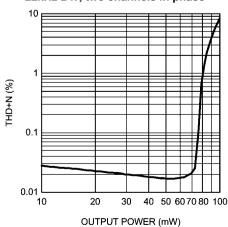
30006824

THD+N vs Output Power V_{DD} = 3V, R_L = 32 Ω , f = 1kHz 22kHz BW, two channels in phase



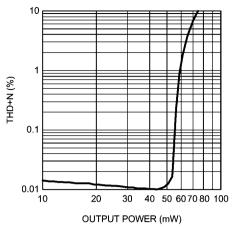
30006825

THD+N vs Output Power V_{DD} = 3.6V, R_L = 16 Ω , f = 1kHz 22kHz BW, two channels in phase



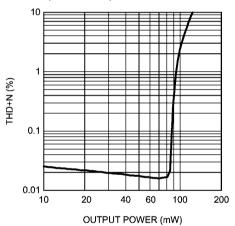
300068c9

THD+N vs Output Power $V_{DD}=3.6V,\,R_L=32\Omega$ f = 1kHz, 22kHz BW, one channel enabled



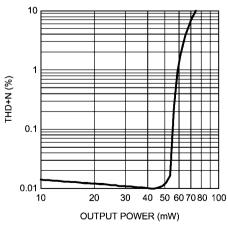
300068d0

THD+N vs Output Power $V_{DD}=4.2V,\,R_L=16\Omega$ f = 1kHz, 22kHz BW, one channel enabled



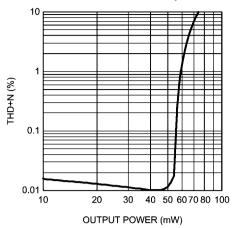
300068d4

THD+N vs Output Power $V_{DD}=4.2V,\,R_L=32\Omega$ f = 1kHz, 22kHz BW, one channel enabled



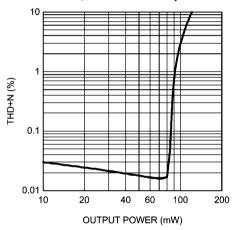
300068d6

THD+N vs Output Power $V_{DD}=3.6V,\,R_L=32\Omega,\,f=1$ kHz 22kHz BW, two channels in phase



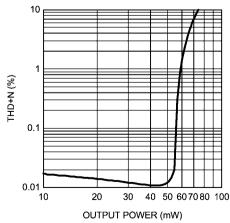
300068d1

THD+N vs Output Power V_{DD} = 4.2V, R_L = 16 Ω , f = 1kHz 22kHz BW, two channels in phase

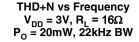


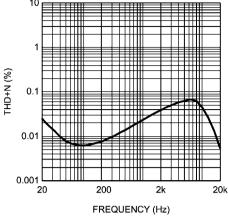
300068d5

THD+N vs Output Power V_{DD} = 4.2V, R_L = 32 Ω , f = 1kHz 22kHz BW, two channels in phase



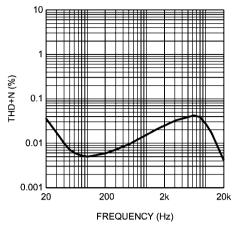
300068d7





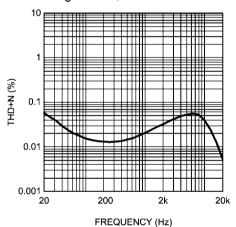
30006822

THD+N vs Frequency $V_{DD} = 3V$, $R_L = 32\Omega$ $P_O = 20$ mW, 22kHz BW



30006823

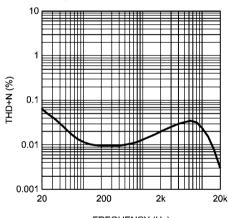
THD+N vs Frequency V_{DD} = 3.6V, R_L = 16 Ω P_O = 30mW, 22kHz BW



300068c4

300068c6

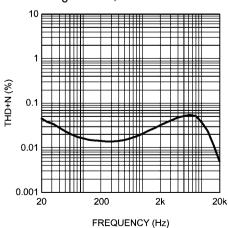
THD+N vs Frequency V_{DD} = 3.6V, R_L = 32 Ω P_O = 30mW, 22kHz BW



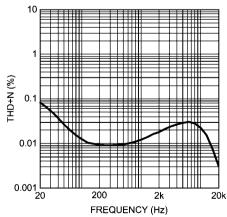
FREQUENCY (Hz)

300068c5

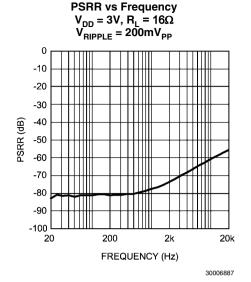
THD+N vs Frequency V_{DD} = 4.2V, R_L = 16 Ω P_0 = 30mW, 22kHz BW

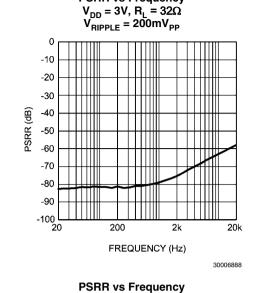


THD+N vs Frequency V_{DD} = 4.2V, R_L = 32 Ω P_O = 30mW, 22kHz BW

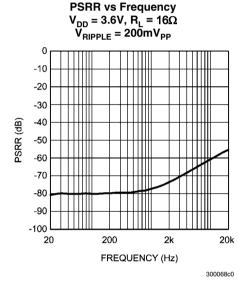


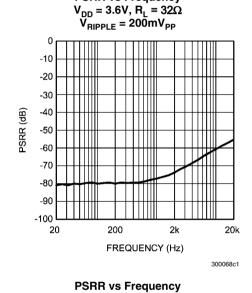
300068c7

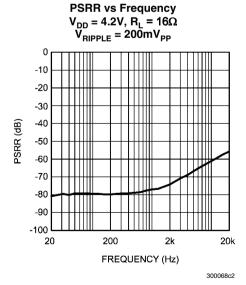


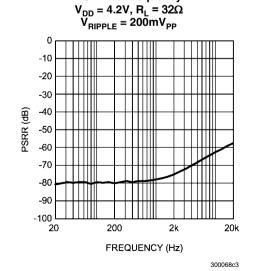


PSRR vs Frequency





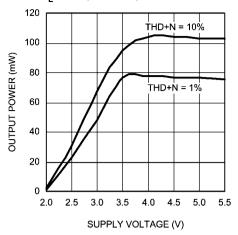




www.national.com

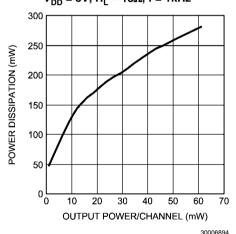
9

Output Power vs Supply Voltage $R_1 = 16\Omega$, f = 1kHz, 22kHz BW

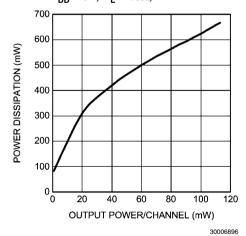


30006885

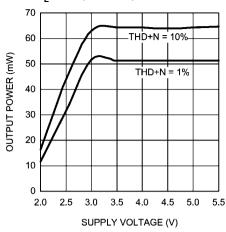
Power Dissipation vs Output Power $V_{DD}=3V,\,R_L=16\Omega,\,f=1kHz$



Power Dissipation vs Output Power $V_{DD} = 5V, R_L = 16\Omega, f = 1kHz$

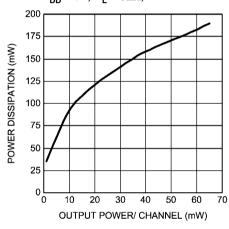


Output Power vs Supply Voltage $R_1 = 32\Omega$, f = 1kHz, 22kHz BW



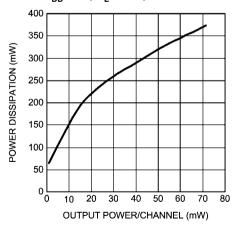
30006886

Power Dissipation vs Output Power $V_{DD} = 3V$, $R_L = 32\Omega$, f = 1kHz



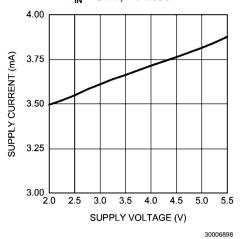
30006895

Power Dissipation vs Output Power $V_{DD} = 5V$, $R_L = 32\Omega$, f = 1kHz

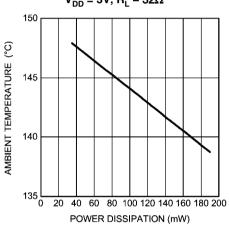


30006897

Supply Current vs Supply Voltage $V_{\rm IN}$ = GND, No Load

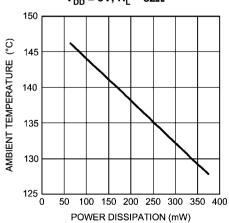


Power Derating Curve $V_{DD} = 3V$, $R_L = 32\Omega$

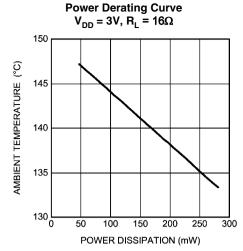


30006891

Power Derating Curve $V_{DD} = 5V$, $R_L = 32\Omega$

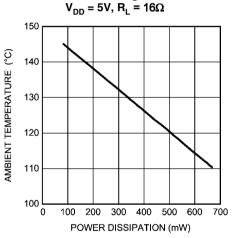


30006893



30006890

Power Derating Curve



30006892

Application Information

SUPPLY VOLTAGE SEQUENCING

It is a good general practice to first apply the supply voltage to a CMOS device before any other signal or supply on other pins. This is also true for the LM48860 audio amplifier which is a CMOS device.

Before applying any signal to the inputs or shutdown pins of the LM48860, it is important to apply a supply voltage to the V_{DD} pins. After the device has been powered, signals may be applied to the shutdown pins (see MICRO POWER SHUTDOWN) and input pins.

ELIMINATING THE OUTPUT COUPLING CAPACITOR

The LM48860 features a low noise inverting charge pump that generates an internal negative supply voltage. This allows the outputs of the LM48860 to be biased about GND instead of a nominal DC voltage, like traditional headphone amplifiers. Because there is no DC component, the large DC blocking capacitors (typically 220µF) are not necessary. The coupling capacitors are replaced by two, small ceramic charge pump capacitors, saving board space and cost.

Eliminating the output coupling capacitors also improves low frequency response. In traditional headphone amplifiers, the headphone impedance and the output capacitor form a high pass filter that not only blocks the DC component of the output, but also attenuates low frequencies, impacting the bass response. Because the LM48860 does not require the output coupling capacitors, the low frequency response of the device is not degraded by external components.

In addition to eliminating the output coupling capacitors, the ground referenced output nearly doubles the available dynamic range of the LM48860 when compared to a traditional headphone amplifier operating from the same supply voltage.

OUTPUT TRANSIENT ('CLICK AND POPS') ELIMINATED

The LM48860 contains advanced circuitry that virtually eliminates output transients ('clicks and pops'). This circuitry prevents all traces of transients when the supply voltage is first applied or when the part resumes operation after coming out of shutdown mode.

AMPLIFIER CONFIGURATION EXPLANATION

As shown in Figure 2, the LM48860 has two internal operational amplifiers. The two amplifiers have internally configured gain.

Since this is an output ground-referenced amplifier, the LM48860 does not require output coupling capacitors.

POWER DISSIPATION

From the graph (THD+N vs Output Power , $V_{DD}=3V$, $R_L=16\Omega$, f=1kHz, 22kH BW, two channels in phase, page 6) assuming a 3V power supply and a 16Ω load, the maximum power dissipation point and thus the maximum package dissipation point is 281mW. The maximum power dissipation point obtained must not be greater than the power dissipation that results from Equation 1.

$$P_{DMAX} = (T_{JMAX} - T_A) / (\theta_{JA})$$
 (1)

For the micro SMD package $\theta_{JA} = 59.3^{\circ}$ C/W. $T_{JMAX} = 150^{\circ}$ C for the LM48860. Depending on the ambient temperature, T_A , of the system surroundings, Equation 1 can be used to find the maximum internal power dissipation supported by the IC packaging. If the maximum power dissipation from the

graph is greater than that of Equation 1, then either the supply voltage must be decreased, the load impedance increased or T_A reduced (see power derating curves). For the application of a 5V power supply, with a 16Ω load, the maximum ambient temperature possible without violating the maximum junction temperature is approximately $110^{\circ}C$ provided that device operation is around the maximum power dissipation point. Power dissipation is a function of output power and thus, if typical operation is not around the maximum power dissipation point, the ambient temperature may be increased accordingly.

POWER SUPPLY BYPASSING

As with any power amplifier, proper supply bypassing is critical for low noise performance and high power supply rejection. Applications that employ a 3V power supply typically use a 4.7 μ F capacitor in parallel with a 0.1 μ F ceramic filter capacitor to stabilize the power supply's output, reduce noise on the supply line, and improve the supply's transient response. Keep the length of leads and traces that connect capacitors between the LM48860's power supply pin and ground as short as possible.

MICRO POWER SHUTDOWN

The voltage applied to the $\overline{SD_LC}$ (shutdown left channel) pin and the $\overline{SD_RC}$ (shutdown right channel) pin controls the LM48860's shutdown function. When active, the LM48860's micropower shutdown feature turns off the amplifiers' bias circuitry, reducing the supply current. The trigger point is 0.45V for a logic-low level, and 1.2V for logic-high level. The low 0.01µA (typ) shutdown current is achieved by applying a voltage that is as near as ground a possible to the $\overline{SD_LC}/\overline{SD_RC}$ pins. A voltage that is higher than ground may increase the shutdown current. Do not let $\overline{SD_LC}/\overline{SD_RC}$ float, connect either to high or low.

SELECTING PROPER EXTERNAL COMPONENTS

Optimizing the LM48860's performance requires properly selecting external components. Though the LM48860 operates well when using external components with wide tolerances, best performance is achieved by optimizing component values.

Charge Pump Capacitor Selection

Use low ESR (equivalent series resistance) (<100m Ω) ceramic capacitors with an X7R dielectric for best performance. Low ESR capacitors keep the charge pump output impedance to a minimum, extending the headroom on the negative supply. Higher ESR capacitors result in reduced output power from the audio amplifiers.

Charge pump load regulation and output impedance are affected by the value of the flying capacitor (C4). A larger valued C4 (up to 3.3uF) improves load regulation and minimizes charge pump output resistance. Beyond 3.3uF, the switch-on resistance dominates the output impedance.

The output ripple is affected by the value and ESR of the output capacitor (C3). Larger capacitors reduce output ripple on the negative power supply. Lower ESR capacitors minimize the output ripple and reduce the output impedance of the charge pump.

The LM48860 charge pump design is optimized for 2.2uF, low ESR, ceramic, flying and output capacitors.

Input Capacitor Value Selection

Amplifying the lowest audio frequencies requires high value input coupling capacitors (C1 and C2 in Figure 1). A high value capacitor can be expensive and may compromise space efficiency in portable designs. In many cases, however, the

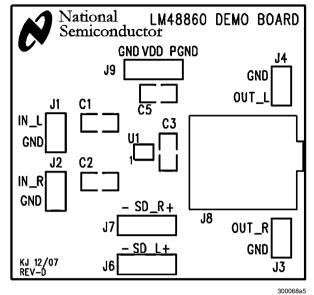
speakers used in portable systems, whether internal or external, have little ability to reproduce signals below 150Hz. Applications using speakers with this limited frequency response reap little improvement by using high value input and output capacitors.

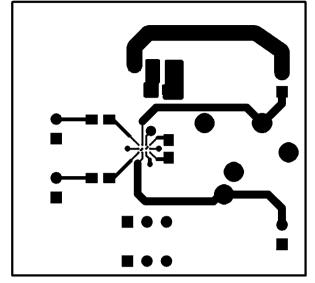
As shown in Figure 1, the internal input resistor, R_i and the input capacitors, C1 and C2, produce a -3dB high-pass filter cutoff frequency that is found using Equation (2).

$$f_{i-3dB} = 1 / 2\pi R_{IN}C$$
 (Hz) (2)

The value of $R_{\rm IN}$ can be found in the *Electrical Characteristics* tables.

Demonstration Board PCB Layout

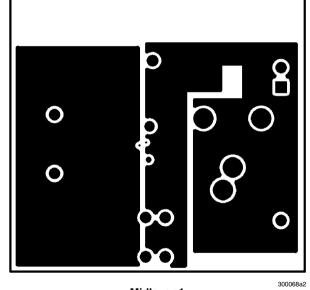


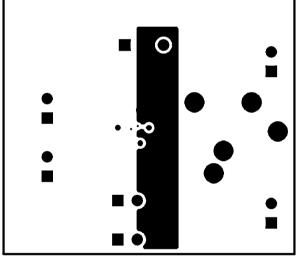


Top Silkscreen

Top Layer



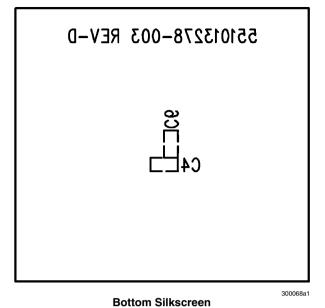


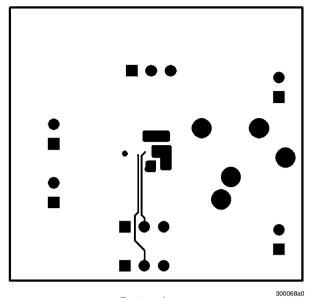


Midlayer 1

Midlayer 2

300068a3



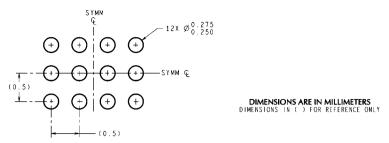


Bottom Layer

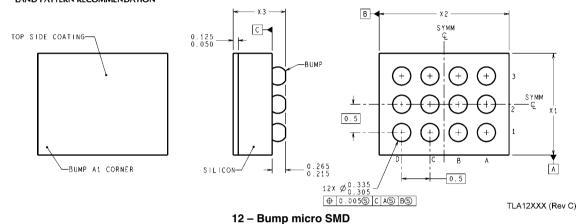
Revision History

Rev	Date	Description		
1.0	01/16/08	Initial release.		
1.01	01/29/08	Text edits.		
1.02	02/14/08	Fixed typos (x-axis) on few curves.		
1.03	10/17/08	Edited the X1 and X2 limits under the Physical Dimension section.		

Physical Dimensions inches (millimeters) unless otherwise noted



LAND PATTERN RECOMMENDATION



Order Number LM48860TL

NS Package Number TLA12XXX

X1 = 1.5±0.03mm, X2 = 2.0±0.03mm, X3 = 0.600±0.075mm,

Notes

For more National Semiconductor product information and proven design tools, visit the following Web sites at:

Pr	oducts	Design Support		
Amplifiers	www.national.com/amplifiers	WEBENCH	www.national.com/webench	
Audio	www.national.com/audio	Analog University	www.national.com/AU	
Clock Conditioners	www.national.com/timing	App Notes	www.national.com/appnotes	
Data Converters	www.national.com/adc	Distributors	www.national.com/contacts	
Displays	www.national.com/displays	Green Compliance	www.national.com/quality/green	
Ethernet	www.national.com/ethernet	Packaging	www.national.com/packaging	
Interface	www.national.com/interface	Quality and Reliability	www.national.com/quality	
LVDS	www.national.com/lvds	Reference Designs	www.national.com/refdesigns	
Power Management	www.national.com/power	Feedback	www.national.com/feedback	
Switching Regulators	www.national.com/switchers			
LDOs	www.national.com/ldo			
LED Lighting	www.national.com/led			
PowerWise	www.national.com/powerwise			
Serial Digital Interface (SDI)	www.national.com/sdi			
Temperature Sensors	www.national.com/tempsensors			
Wireless (PLL/VCO)	www.national.com/wireless			

THE CONTENTS OF THIS DOCUMENT ARE PROVIDED IN CONNECTION WITH NATIONAL SEMICONDUCTOR CORPORATION ("NATIONAL") PRODUCTS. NATIONAL MAKES NO REPRESENTATIONS OR WARRANTIES WITH RESPECT TO THE ACCURACY OR COMPLETENESS OF THE CONTENTS OF THIS PUBLICATION AND RESERVES THE RIGHT TO MAKE CHANGES TO SPECIFICATIONS AND PRODUCT DESCRIPTIONS AT ANY TIME WITHOUT NOTICE. NO LICENSE, WHETHER EXPRESS, IMPLIED, ARISING BY ESTOPPEL OR OTHERWISE, TO ANY INTELLECTUAL PROPERTY RIGHTS IS GRANTED BY THIS DOCUMENT.

TESTING AND OTHER QUALITY CONTROLS ARE USED TO THE EXTENT NATIONAL DEEMS NECESSARY TO SUPPORT NATIONAL'S PRODUCT WARRANTY. EXCEPT WHERE MANDATED BY GOVERNMENT REQUIREMENTS, TESTING OF ALL PARAMETERS OF EACH PRODUCT IS NOT NECESSARILY PERFORMED. NATIONAL ASSUMES NO LIABILITY FOR APPLICATIONS ASSISTANCE OR BUYER PRODUCT DESIGN. BUYERS ARE RESPONSIBLE FOR THEIR PRODUCTS AND APPLICATIONS USING NATIONAL COMPONENTS. PRIOR TO USING OR DISTRIBUTING ANY PRODUCTS THAT INCLUDE NATIONAL COMPONENTS, BUYERS SHOULD PROVIDE ADEQUATE DESIGN, TESTING AND OPERATING SAFEGUARDS.

EXCEPT AS PROVIDED IN NATIONAL'S TERMS AND CONDITIONS OF SALE FOR SUCH PRODUCTS, NATIONAL ASSUMES NO LIABILITY WHATSOEVER, AND NATIONAL DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY RELATING TO THE SALE AND/OR USE OF NATIONAL PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS PRIOR WRITTEN APPROVAL OF THE CHIEF EXECUTIVE OFFICER AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

Life support devices or systems are devices which (a) are intended for surgical implant into the body, or (b) support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in a significant injury to the user. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system or to affect its safety or effectiveness.

National Semiconductor and the National Semiconductor logo are registered trademarks of National Semiconductor Corporation. All other brand or product names may be trademarks or registered trademarks of their respective holders.

Copyright© 2008 National Semiconductor Corporation

For the most current product information visit us at www.national.com



National Semiconductor Americas Technical Support Center Email: support@nsc.com Tel: 1-800-272-9959 National Semiconductor Europe Technical Support Center Email: europe.support@nsc.com German Tel: +49 (0) 180 5010 771 English Tel: +44 (0) 870 850 4288 National Semiconductor Asia Pacific Technical Support Center Email: ap.support@nsc.com National Semiconductor Japan Technical Support Center Email: jpn.feedback@nsc.com